SKDH 115



SEMIPONTTM 5

Half Controlled 3-phase Bridge Rectifier

SKDH 115

Target Data

Features

- Compact design
- Two screws mounting
- Heat transfer and isolation through direct copper board (low R _{th})
- Low resistance in steady-state and high reliability
- High surge currents
- UL -recognized, file no. E 63 532

Typical Applications

- For DC drives with a fixed direction of rotation
- Controlled field rectifier for DC motors
- Controlled battery charger

	•	$(1_{s} = 00 \ C)$		
1200	1200	SKDH 115/12	SKDH 115/12	
1600 1600		SKDH 115/16		
Symbol	Conditions	Values	Units	
I _D	T _s = 80 °C	110	A	
-	T _{vi} = 25 °C; 10 ms	1050	A	
I _{TSM} , I _{FSM}	$T_{vj} = 125 \text{ °C}; 10 \text{ ms}$ $T_{vi} = 125 \text{ °C}; 10 \text{ ms}$	950	A	
i²t	$T_{vj} = 25 \text{ °C}; 8,3 \dots 10 \text{ ms}$		A ² s	
	$T_{vi} = 125 \text{ °C}; 8,3 \dots 10 \text{ n}$		A ² s	
	.,			
V _T , V _F	$T_{vj} = 25 \text{ °C}; I_T, I_F = 120A$	max. 1,8		
V _{T(TO)} / Vf(TO)	T _{vj} = 125 °C;	max. 1,1	v	
r _T	T _{vi} = 125 °C	max. 6	mΩ	
I _{DD} ; I _{RD}	$T_{vj} = 125 \text{ °C}; V_{DD} = V_{DR}$	m; V _{RD} = V _{RRM} max. 20	mA	
t _{gd}	$T_{vi} = °C; I_G = A; di_G/dt =$	A/μs	μs	
t _{gr}	$V_{\rm D} = \cdot V_{\rm DRM}$		μs	
(dv/dt) _{cr}	T _{vi} = 125 °C	max. 500	V/µs	
(di/dt) _{cr}	$T_{vi} = 125 \text{ °C}; f = 5060$		A/µs	
t _q	$T_{vi} = 125 \text{ °C; typ.}$	150	μs	
I _H	T _{vi} = 25 °C; typ. / max.	- / 200	mA	
L.	$T_{vi} = 25$ °C; R _G = 33 Ω	- / 400	mA	
V _{GT}	T _{vi} = 25 °C; d.c.	min. 3	V	
I _{GT}	T _{vi} = 25 °C; d.c.	min. 150	mA	
V _{GD}	T _{vi} = 125 °C; d.c.	max. 0,25	V	
I _{GD}	T _{vi} = 125 °C; d.c.	max. 5	mA	
0.5	.,		K/W	
			K/W	
R _{th(j-s)}	per thiristor / diode	0,84	K/W	
т		- 40 + 125	°C	
T _{vj} T _{stg}		- 40 + 125	°C	
T _{solder}	terminals	260	°C	
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s /		v	
v _{isol} M _s	to heatsink	2,5	Nm	
M _s M _t		2,0	Nm	
m	approx.	75	g	
Case	SEMIPONT 5	G 61		
0000		5.01		

 $I_D = 110 \text{ A}$ (full conduction)

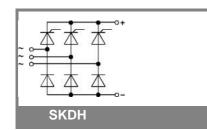
(T_s = 80 °C)

 V_{RRM}, V_{DRM}

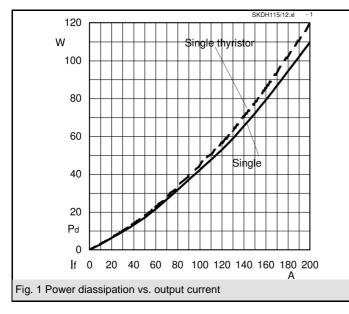
V

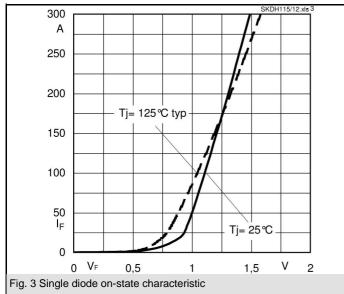
 V_{RSM}

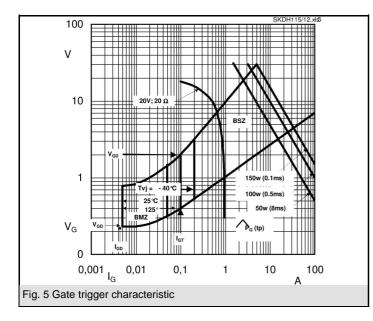
ν

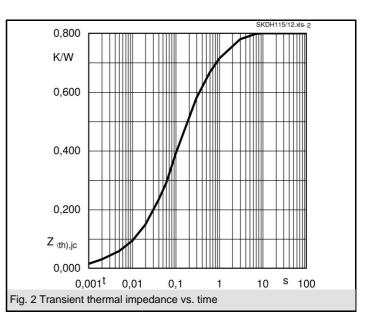


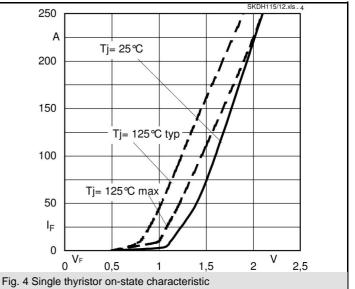
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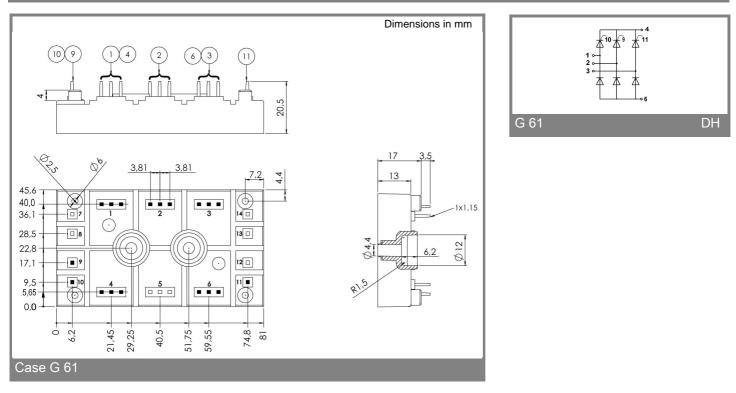








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